

# NEC'S SINGLE TR. OUTPUT, HIGH COLLECTOR-EMITTER VOLTAGE, 4-PIN ULTRA SMALL FLAT LEAD OPTOCOUPLER

PS2913-1

# **FEATURES**

- ULTRA SMALL FLAT LEAD PACKAGE: 4.6 (L) x 2.5 (W) x 2.1 (H) mm
- ISOLATION DISTANCE: 0.4 mm MIN
- HIGH COLLECTOR TO EMITTER VOLTAGE: VCEO = 120 V
- HIGH ISOLATION VOLTAGE BV = 2500 Vr.m.s.
- AVAILABLE IN TAPE AND REEL: PS2913-1-F3, F4: 3500 pcs/reel

# **DESCRIPTION**

NEC's PS2913-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor is one package for high density mounting applications. This device is housed in an ultra small flat-lead package which realizes a reduction in mounting area of about 30% compared with the PS28XX series.

# **APPLICATIONS**

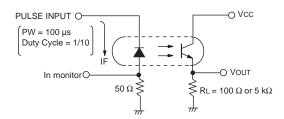
- HYBRID IC
- POWER SUPPLY

# **ELECTRICAL CHARACTERISTICS** (TA = 25°C)

PART NUMBER						PS2913-1		
SYMBOLS		PARAMETERS		UNITS	MIN	TYP	MAX	
Diode	VF	Forward Voltage, IF = 1 mA		V	0.9	1.1	1.3	
	IR	Reverse Current, VR = 5 V		μΑ			5	
	Ст	Terminal Capacitance, V = 0, f = 1.0 MHz		pF		15		
Transistor	ICEO	Collector to Emir	tter Dark Current, IF = 1 mA, VcE = 120 V	nA			100	
Coupled	CTR	Current Transfer Ratio (Ic/IF), IF = 1 mA, VcE = 5 V		%	50	100	200	
	VCE(sat)	Collector Saturation Voltage, IF = 1 mA, Ic = 0.2 mA		V		0.13	0.3	
	Rı-o	Isolation Resistance, VI-O = 1.0 kVDC		Ω	10 <sup>11</sup>			
Cou	Cı-o	Ci-O Isolation Capacitance, V = 0 V, f = 1.0 MHz		pF		0.4		
	tr	Rise Time <sup>1</sup>	$Vcc = 5 \text{ V, } Ic = 2 \text{ mA}, \text{ RL} = 100 \Omega$	μS		10		
	tf	Fall Time <sup>1</sup>		μS		10		
	ton	On Time <sup>1</sup>	$Vcc = 5 \text{ V, IF} = 1 \text{ mA}, \text{ RL} = 5 \text{ k}\Omega$	μS		80		
	ts	Storage Time <sup>1</sup>		μS		5		
	tF	Off Time <sup>1</sup>		μS		50		

### Note:

1. Test Circuit for Switching Time



# ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS			
Diode	Diode					
lF	Forward Current (DC)	mA	50			
ΔIF/°C	Forward Current Derating	mA/°C	0.5			
IF (Peak)	Peak Forward Current <sup>2</sup>	А	0.5			
PD	Power Dissipation	mW	60			
VR	Reverse Voltage	V	6			
Transistor	Transistor					
VCEO	Collector to Emitter Voltage	V	120			
VECO	Emitter to Collector Voltage	V	6			
Ic	Collector Current	mA	30			
ΔPc/°C	Power Dissipation Derating	mW/°C	1.2			
Pc	Power Dissipation	mW	120			
Coupled						
Viso	Isolation Voltage <sup>3</sup>	Vr.m.s.	2500			
PT	Total Power Dissipation	mW	160			
TA	Operating Ambient Temp.	°C	-55 to +100			
Tstg Storage Temperature		°C	-55 to +150			

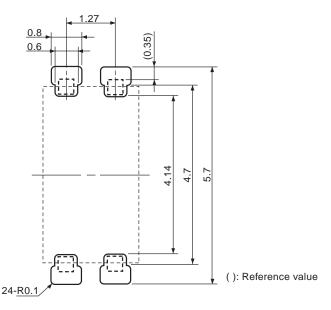
### Notes:

- Operation in excess of any one of these parameters may result in permanent damage.
- 2. PW = 100  $\mu$ s, Duty Cycle = 1%.
- 3. AC voltage for 1 minute at TA = 25°C, RH = 60% between input and output.

# ORDERING INFORMATION

PART NUMBER	PACKING STYLE
PS2913-1-F3	Embossed Tape 3500 pcs/reel
PS2913-1-F4	

# RECOMMENDED MOUNT PAD DIMENSIONS (Units in mm)



### Remark:

This drawing is considered to meet air and outer creepage distance 4.0 minimum. All dimensions in this figure must be evaluated before use.

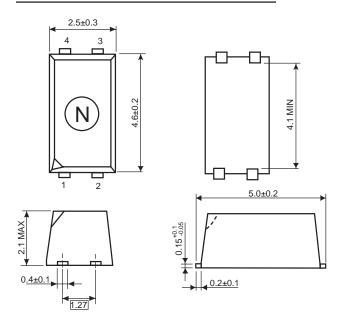
# **OPTOCOUPLER CONSTRUCTION**

PARAMETER	UNITS (MIN)		
Air Distance	4 mm		
Creepage Distance	4 mm		
Isolation Distance	0.4 mm		

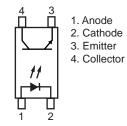
# **CAUTIONS REGARDING NOISE:**

Be aware that when voltage is applied suddenly between the optocoupler's input and outout or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

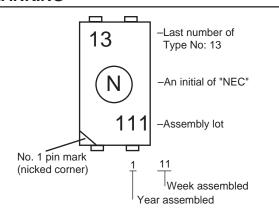
# **OUTLINE DIMENSIONS** (Units in mm)



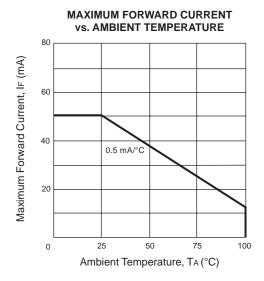
# **TOP VIEW**

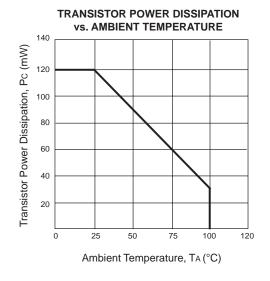


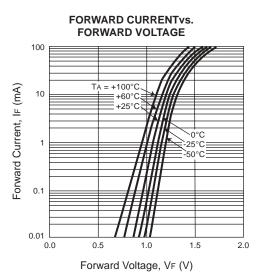
# **MARKING**

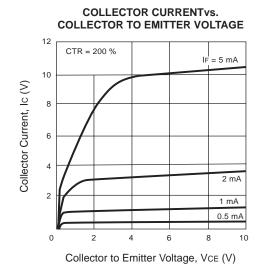


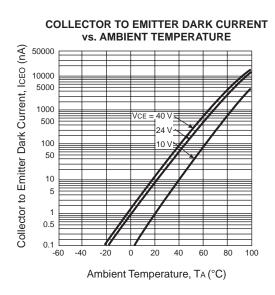
# TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)

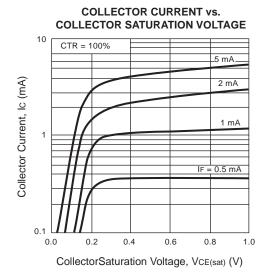






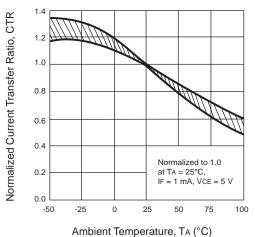




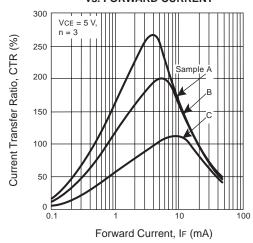


# **TYPICAL CHARACTERISTICS** (TA = 25°C, unless otherwise specified)

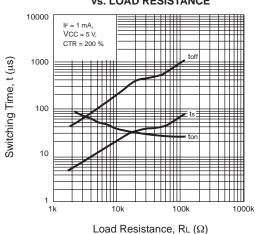




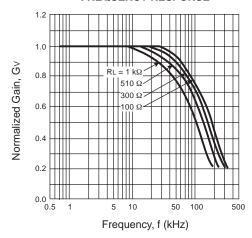
# CURRENT TRANSFER RATIO vs. FORWARD CURRENT



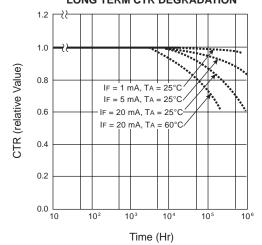
# SWITCHING TIME vs. LOAD RESISTANCE



# **FREQUENCY RESPONSE**



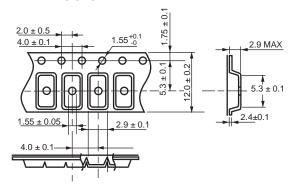
# LONG TERM CTR DEGRADATION



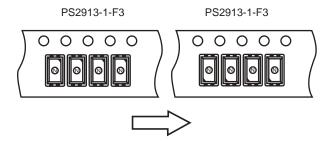
**REMARK:** The graphs indicate nominal characteristics.

# TAPING SPECIFICATIONS (Units in mm)

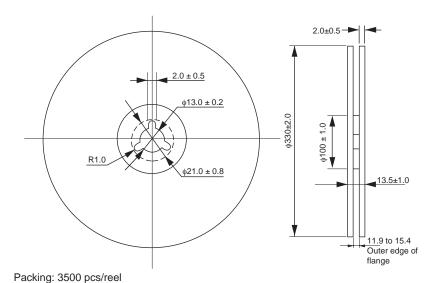
# TAPE OUTLINE AND DIMENSIONS



# TAPE DIRECTION



# REEL OUTLINE AND DIMENSIONS



# RECOMMENDED SOLDERING CONDITIONS

# (1) Infrared reflow soldering

Peak reflow temperature
 260 °C or below (package surface temperature)

Time of peak reflow temperature
 Time of temperature higher than 220 °C
 60 seconds or less

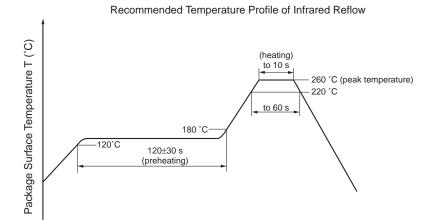
Time to preheat temperature from 120 to 180°C 120±30 s

Number of reflows
 Three

- Flor

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is

recommended).



Time (s)

# (2) Wave soldering

Temperature 260 °C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times
 One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux)

with a maximum chlorine content of 0.2 Wt % is recommended).

# (3) Cautions

• Fluxes Avoid removing the residual flux with chlorine-based cleaning solvent after a reflow process.

# **USAGE CAUTIONS**

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature ad high humidity.

### Life Support Applications

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